

### Solid State Devices, Inc.

14701 Firestone Blvd \* La Mirada, Ca 90638 Phone: (562) 404-4474 \* Fax: (562) 404-1773 ssdi@ssdi-power.com \* www.ssdi-power.com

# SDR3A and SDR3ASMS thru SDR3N and SDR3NSMS

3.0 AMPS 50 — 1200 VOLTS 50 — 80 nsec ULTRA FAST RECTIFIER

# Designer's Data Sheet

Part Number/Ordering Information  $^{1/2}$ 

SDR1

L Screening 2/

= Not Screened

TX = TX Level

TXV = TXV

S = S Level

L Package Type
\_\_ = Axial Leaded

SMS = Surface Mount Square Tab

Family A = 50 V

A = 50 V J = 600VB = 100V K = 800V

D = 200V

M = 1000V

G = 400V

N = 1200V

### **FEATURES:**

Ultra Fast Recovery: 50-80 ns Max @ 25°C 4/ 85-125 ns Max @ 100°C 4/

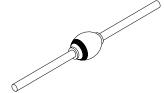
- Single Chip Construction
  - PIV to 1200 Volts
- Low Reverse Leakage Current
- Hermetically Sealed
- For High Efficiency Applications
- Available in Axial and Surface Mount Versions
- Metallurgically Bonded
- TX, TXV, and S-Level Screening Available

MAXIMUM RATINGS 3/				
RATING		SYMBOL	VALUE	UNIT
Peak Repetitive Reverse Voltage And DC Blocking Voltage	SDR3A and SDR3ASMS SDR3B and SDR3BSMS SDR3D and SDR3DSMS SDR3G and SDR3GSMS SDR3J and SDR3JSMS SDR3K and SDR3KSMS SDR3M and SDR3MSMS SDR3M and SDR3NSMS	$egin{array}{c} V_{RRM} \ V_{RWM} \ V_{R} \end{array}$	50 100 200 400 600 800 1000 1200	Volts
Rectified Forward Forward Current (Resistive Load, 60 Hz, Sine Wave, T <sub>A</sub> = 25°C)		$I_0$	3	Amp
Peak Surge Current (8.3 msec Pulse, Half Sine Wave Superimposed on Io, allow junction to reach equilibrium between pulses, $T_A = 25^{\circ}C$ )		$I_{FSM}$	75	Amps
Operating & Storage Temperature		$T_{\text{OP}}$ and $T_{\text{STG}}$	-65 to +175	°C
Thermal Resistance, Junction to Lead, L = 3/8"  Junction to End Tab		$egin{aligned} \mathbf{R}_{ heta \mathrm{JL}} \ \mathbf{R}_{ heta \mathrm{JE}} \end{aligned}$	20 14	°C/W

#### **NOTES:**

- 1/ For Ordering Information, Price, and Availability- Contact Factory.
- 2/ Screened to MIL-PRF-19500.
- 3/ Unless Otherwise Specified, All Electrical Characteristics @25°C.
- $\underline{4}$ / Recovery Conditions:  $I_F = 0.5$  Amp,  $I_R = 1.0$  Amp,  $I_{RR}$  to .25 Amp.

**Axial Leaded** 



**SMS** 



**NOTE:** All specifications are subject to change without notification. SCD's for these devices should be reviewed by SSDI prior to release.

DATA SHEET #: RU0013D

DOC

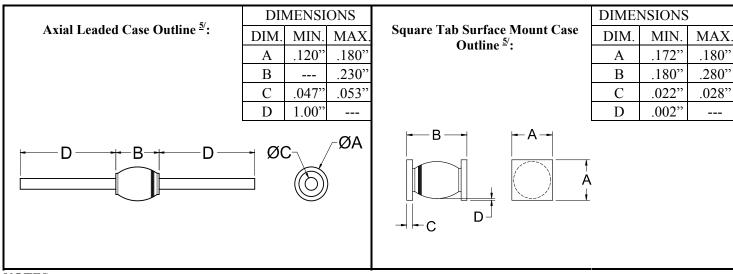


id State Devices, Inc.

14701 Firestone Blvd \* La Mirada, Ca 90638 Phone: (562) 404-4474 \* Fax: (562) 404-1773 ssdi@ssdi-power.com \* www.ssdi-power.com

# SDR3A and SDR3ASMS thru SDR3N and SDR3NSMS

ELECTRICAL CHARACTERISTICS 3/						
CHARACTERISTICS		SYMBOL	VALUE	UNIT		
Instantaneous Forward Voltage Drop ( $I_F = 1 \text{Adc}, 300\text{-}500  \mu\text{s} \text{ Pulse}, T_A = 25^{\circ}\text{C}$ )	SDR3A thru SDR3J SDR3K thru SDR3N	$\mathbf{V}_{\mathrm{F1}}$	1.35 1.90	Vdc		
Instantaneous Forward Voltage Drop ( $I_F = 1 \text{Adc}, 300\text{-}500  \mu\text{s} \text{ Pulse}, T_A = -55^{\circ}\text{C}$ )	SDR3A thru SDR3J SDR3K thru SDR3N	$ m V_{F2}$	1.50 2.10	Vde		
Maximum Reverse Leakage Current (Rated $V_R$ , 300 $\mu$ s Pulse Minimum , $T_A$ = 25°C)		$I_{R1}$	5	μΑ		
Maximum Reverse Leakage Current (Rated $V_R$ , 300 $\mu$ s Pulse Minimum , $T_A$ = 100°C)		$I_{R2}$	500	μΑ		
Junction Capacitance (VR = $10$ Vdc, $T_A = 25$ °C, $f = 1$ MHz)		$C_{\mathrm{J}}$	50	pf		
Maximum Reverse Recovery Time 4/	SDR3A thru SDR3J SDR3K SDR3M SDR3N	t <sub>rr</sub>	50 60 70 80	ns		



### **NOTES:**

- 1/ For Ordering Information, Price, and Availability- Contact Factory.
- 2/ Screened to MIL-PRF-19500.
- 3/ Unless Otherwise Specified, All Electrical Characteristics @25°C.
- $\underline{\textbf{4}}/$  Recovery Conditions:  $I_F = 0.5$  Amp,  $I_R = 1.0$  Amp,  $I_{RR}$  to .25 Amp.
- 5/ For information on operating curves, contact factory.